

# XDPL8210 CDM10VD 35 W reference design with IPN80R900P7

For LED driver with isolated 0 to 10 V dimming and dim-to-off operation

Order code: REF-XDPL8210-U35W

### About this document

### Scope and purpose

This document is an engineering report for the XDPL8210 CDM10VD 35 W reference design (part ordering number: REF-XDPL8210-U35W; SP number: SP001886070), which uses Infineon's XDPL8210 High Power Factor (HPF) Flyback controller, CDM10VD isolated 0 to 10 V dimming interface IC and IPN80R900P7 MOSFET.

### **Intended audience**

Power supply design engineers, field application engineers.

### **Table of contents**

It this document	1
e of contents	1
Introduction and safety information	2
Design features	3
Board specifications	4
-	
Line and load regulation	9
System efficiency	10
Power Factor (PF) and Total Harmonic Distortion (iTHD)	10
Current harmonics	11
Thermal test	12
Conducted emissions (EN55015B)	14
Dimming	16
Standby power	16
LED current dimming curve	17
PF and iTHD	18
Protections	18
Input UVP and maximum power limitation during brown-outout	18
Input OVP	19
Adaptive output OVP	19
BOM and transformer specifications	21
References	24
sion history	25
	t this document e of contents Introduction and safety information Design features



## **1** Introduction and safety information

The XDPL8210 CDM10VD 35 W reference design is a digitally configurable HPF LED driver with universal AC input of 90 V<sub>rms</sub> to 305 V<sub>rms</sub>, wide output LED load range of 18 V to 54 V, and isolated 0 to 10 V dimming. It has a non-dimmed output current set-point of 830 mA and an output power limitation set-point of 35 W.

The 35 W reference design is ready to be tested out of the box, as shown in **Figure 1**. There is no need for any pre-programming by the user, as the XDPL8210 chip on the reference board has already been burned with the first full configuration set of working parameters.

A simple test set-up can be done by connecting the board's AC input (L – live, N – neutral) to the AC source, the board's output to the LEDs (+, -) and 0 to 10 V dimming input to the DC source, based on **Figure 1**.

# Attention: Lethal voltages are present on this reference design. Do not operate the board unless you are trained to handle high voltage circuits. Do not leave this board unattended when it is powered up.

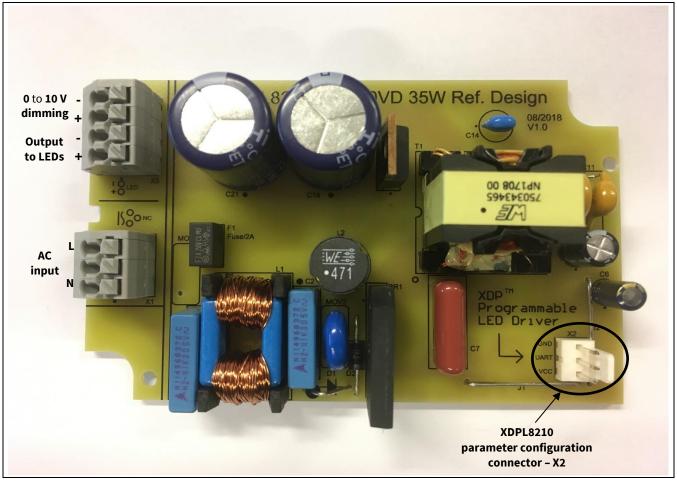


Figure 1

XDPL8210 CDM10VD 35 W reference design

### 2 Design features

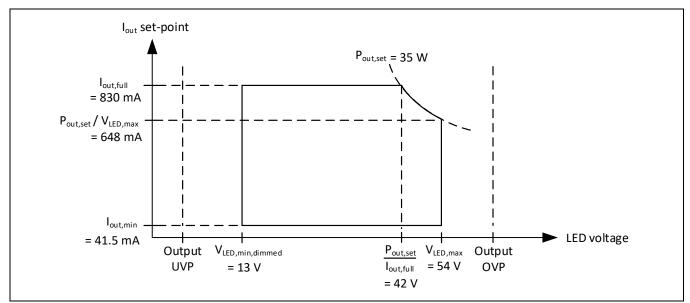
- Primary Side Regulated (PSR) Constant Current (CC) output
- Supports universal input with 90 V<sub>rms</sub> to 305 V<sub>rms</sub>
- HPF and low Total Harmonic Distortion (iTHD)
- High efficiency with QR mode with first valley switching (QRM1) operation at high output power
- High efficiency with frequency controlled Discontinuous Conduction Mode (DCM) operation at medium
   output power
- Dim-to-off operation with low standby power
- Transformer-less IEC60929-compliant isolated 0 to 10 V dimming using CDM10VD
- Maximum output power limit setting
- UL1310 Class 2 output for 54 V LED driver design with adaptive output Over Voltage Protection (OVP)
- Input OVP and Under Voltage (brown-in/brown-out) Protection (UVP)
- Output short protection
- **Configurable dimming parameters**, e.g. dimming curve (linear/quadratic), minimum current, dim-to-off option (enabled/disabled)
- Configurable protection parameters, e.g. protection thresholds and reaction (auto-restart/latch)
- Low Bill of Materials (BOM)

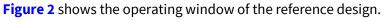
Note: CDM10VD is a device that transmits analog voltage-based signals from a 0 to 10 V dimmer or potentiometer to the dimming or PWM input of a lighting controller IC in the form of a 5 mA current-based PWM signal to drive an external isolated optocoupler. It replaces many components in a traditional solution and reduces BOM and PCB space significantly. For more details about CDM10VD, please visit the Infineon website: https://www.infineon.com/cms/en/product/power/lighting-ics/dimming-interface-ics/cdm10vd/





# **3 Board specifications**





#### Figure 2 Operating window

 Table 1 and Table 2 respectively list the electrical specifications and system protection parameter values of the reference design.

#### Table 1Electrical specifications

Specification	Symbol	Value	Unit
Normal operational AC input voltage	V AC	90 ~ 305	V <sub>rms</sub>
Normal operational AC input frequency	F <sub>line</sub>	47 ~ 63	Hz
Steady-state maximum output current set-point	I <sub>out,full</sub>	830	mA
Steady-state maximum output power limit set-point	P <sub>out,set</sub>	35	W
Steady-state maximum output LED load voltage	V <sub>LED,max</sub>	54	V
Steady-state minimum output LED load voltage (non-dimmed)	V <sub>LED</sub> ,min,non-dimmed	18	V
Steady-state minimum output LED load voltage (dimmed)	VLED,min,dimmed	13	V
Total line, load regulation (non-dimmed)	Δl <sub>out</sub>	±2	%
Dimming input	V <sub>dimmer</sub>	0~10	V
Minimum output current set-point	I <sub>out,min</sub>	41.5	mA
Output current dimming curve shape	Сым	Linear	-
Standby power (V AC = $120 V_{rms}$ to $277 V_{rms}$ ; $V_{DIMMER} = 0 V$ )	$P_{standby}$	180	mW
Dimming input sensing interval during dim-to-off	$\mathbf{t}_{dim,sense,off}$	0.4	S



# XDPL8210 CDM10VD 35 W reference design with IPN80R900P7 For LED driver with isolated 0 to 10 V dimming and dim-to-off operation

### **Board specifications**

Specification	Symbol	Value	Unit
Efficiency (V AC = $120 V_{rms}$ to $277 V_{rms}$ ; $V_{LED} = 42 V$ to 54 V; non-dimming)	η	More than 89	%
Power Factor 1 (V AC = 230 V <sub>rms</sub> ; F <sub>line</sub> = 50 Hz ; V <sub>LED</sub> = 18 V to 54 V; non-dimming)	PF1	More than 0.95	-
Power Factor 2 (V AC = 120 $V_{rms}$ to 277 $V_{rms}$ ; $F_{line}$ = 60 Hz; $V_{LED}$ = 30 V to 54 V; non-	PF <sub>2</sub>	More than 0.92	_
Total Harmonic Distortion 1 (V AC = 230 V <sub>rms</sub> ; F <sub>line</sub> = 50 Hz; V <sub>LED</sub> = 18 V to 54 V; non-dimming)	iTHD <sub>1</sub>	Less than 10	%
Total Harmonic Distortion 2 (V AC = 120 $V_{rms}$ to 277 $V_{rms}$ ; $F_{line}$ = 60 Hz; $V_{LED}$ = 18 V to 54 V; non-	iTHD <sub>2</sub>	Less than 15	%



# XDPL8210 CDM10VD 35 W reference design with IPN80R900P7 For LED driver with isolated 0 to 10 V dimming and dim-to-off operation

**Board specifications** 

#### Table 2 System protection parameter values

System protection parameter	Symbol	Value	Unit
Input OVP level <sup>1</sup>	V <sub>inOV</sub>	352	V <sub>rms</sub>
Maximum input voltage level for start-up <sup>1</sup>	Vin,start,max	326	$V_{\rm rms}$
Brown-in/minimum input voltage level for start-up <sup>1</sup>	V <sub>in,start,min</sub>	80	$V_{\rm rms}$
Brown-out/input UVP level <sup>1</sup>	V <sub>inUV</sub>	63	V <sub>rms</sub>
Output OVP level <sup>1</sup>	V <sub>outOV</sub>	56.9	V
Output OVP level during auto-restart <sup>1</sup>	V <sub>outOV,red</sub>	51.3	V
Regulated mode output UVP level	V <sub>outUV</sub>	6	V
Regulated mode output UVP blanking time <sup>1</sup>	$\mathbf{t}_{VoutUV,blank}$	40	ms
Regulated mode maximum peak output current protection level <sup>1</sup>	I <sub>out,max,peak</sub>	2.1	А
Regulated mode maximum peak output current protection blanking time <sup>1</sup>	$t_{lout,max,peak,blank}$	1.0	ms
Auto-restart speed for regulated mode maximum peak output current protection <sup>1</sup>	Speed <sub>ocp,lout</sub>	Fast	
V <sub>cc</sub> OVP level	V <sub>VCC,max</sub>	24	V
Regulated mode Current Sense (CS) pin voltage level 1 for MOSFET maximum current cycle-by-cycle limit at lowest operational input voltage <sup>1</sup>	V <sub>ocp1</sub>	0.50	v
IC over-temperature protection level <sup>2</sup>	T <sub>critical</sub>	119	°C
Maximum IC temperature for start-up	T <sub>start,max</sub>	115	°C
Input OVP reaction	Reaction <sub>ovP,Vin</sub>	Auto-restart	-
Input UVP reaction	Reaction <sub>UVP,Vin</sub>	Auto-restart	-
Output OVP reaction <sup>1</sup>	Reaction <sub>OVP,Vout</sub>	Auto-restart	-
Start-up output UVP reaction	Reaction <sub>UVP,Vout,start</sub>	Auto-restart	-
Regulated mode output UVP reaction	ReactionUVP,Vout	Auto-restart	-
Regulated mode maximum peak output current protection reaction	Reaction <sub>lout,max,peak</sub>	Auto-restart	-
V <sub>cc</sub> OVP reaction	Reaction <sub>vcc,ovp</sub>	Auto-restart	-
IC over-temperature protection reaction	Reaction	Auto-restart	-
Fast auto-restart time	t <sub>auto,restart,fast</sub>	0.4	s
Auto-restart time <sup>1</sup>	t <sub>auto,restart</sub>	1.6	S

*Note:* The input, output voltage sensing for these protections are estimated from ZCD pin switching signals. To improve the input voltage estimation accuracy, CS pin switching signal is also sensed.

Note:

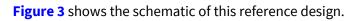
Regulated mode is a controller operating state, which is entered after the start-up phase, to regulate the output.

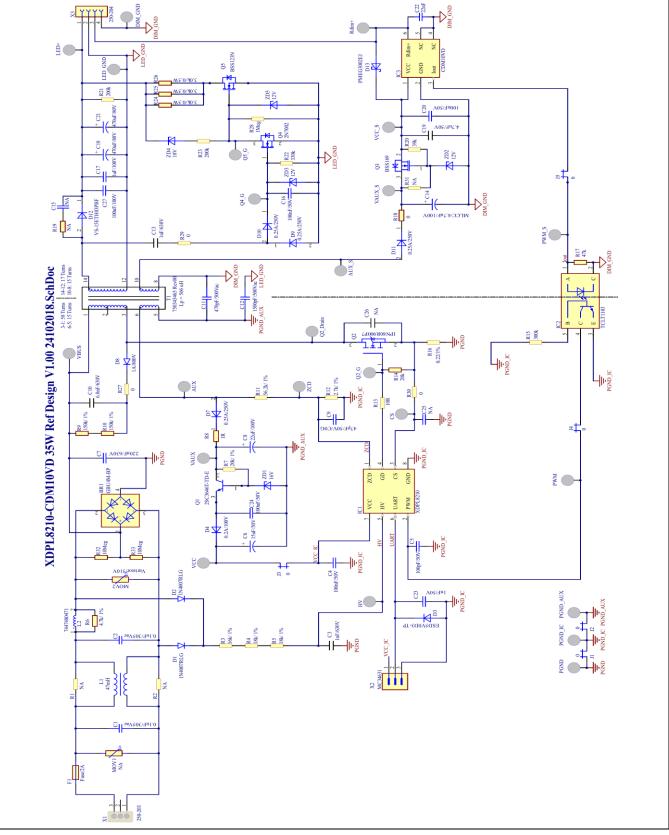
- <sup>2</sup> Configurable up to 143°C (lifetime is not guaranteed when IC operating junction temperature is above 125°C)
- **Engineering Report**

<sup>&</sup>lt;sup>1</sup> Configurable



### 4 Schematic and PCB layout







XDPL8210 CDM10VD 35 W reference design main board schematic



The XDPL8210 CDM10VD 35 W reference design has a single-layer PCB layout design. **Figure 4** and **Figure 5** respectively show the PCB top layout (with dimensions) and bottom layout.

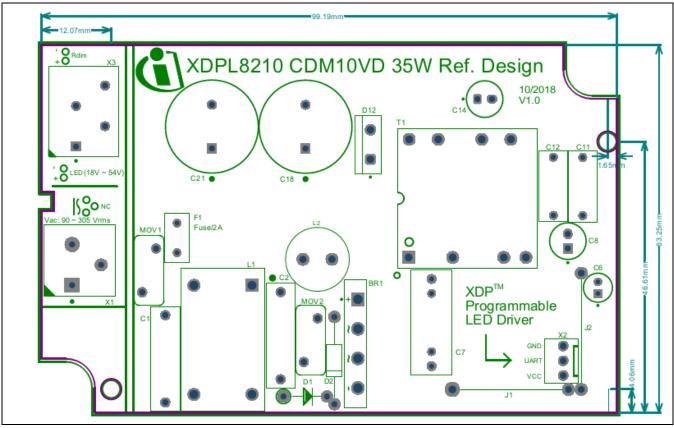


Figure 4 PCB top layout with dimensions

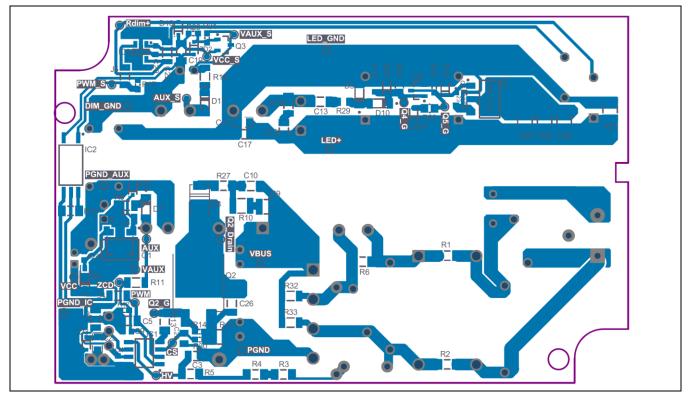


Figure 5 PCB bottom layout Engineering Report

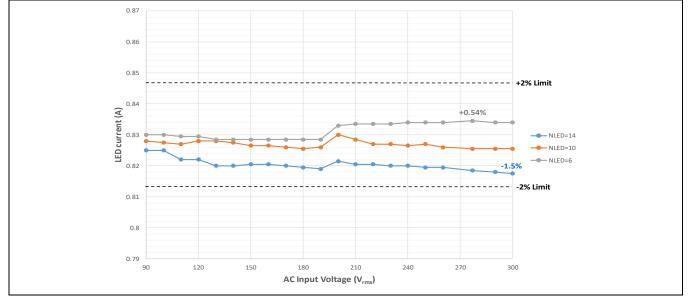
The results shown in this section are based on the evaluation of a single reference board.

#### **Non-dimming** 5.1

The measurement results under non-dimming condition are presented in this section.

#### Line and load regulation 5.1.1

The total line and load regulation of the output current under non-dimming condition is well within ±2 percent, as shown in Figure 6.



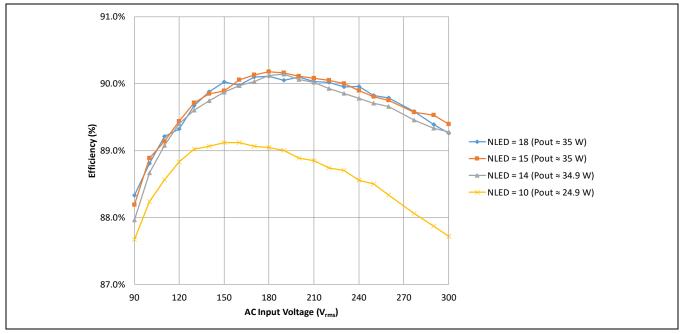
**Figure 6** Line and load regulation test result (non-dimmed output current)

The total line and load regulation of the output power limit under non-dimming condition is within ±1 percent approximately, as shown in Figure 7.





5.1.2 System efficiency



The system efficiency measurements under non-dimming condition are shown in Figure 8.



### 5.1.3 Power Factor (PF) and Total Harmonic Distortion (iTHD)

Across a wide LED load range ( $N_{LED} = 6$  to 18) under non-dimming condition, the PF is above 0.94 with VAC = 230  $V_{rms}$  ( $F_{line} = 50$  Hz), as shown in **Figure 9**.

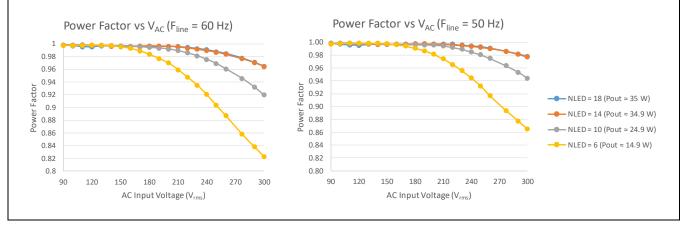
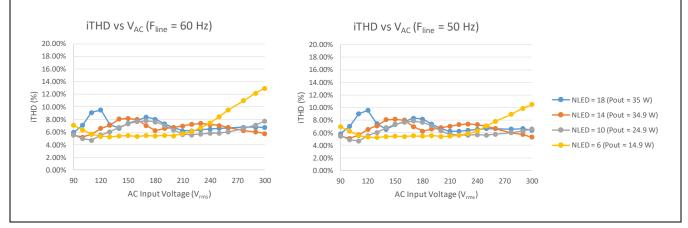


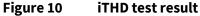
Figure 9 PF test result (non-dimming condition)

Across a wide LED load range ( $N_{LED} = 6$  to 18) under non-dimming condition, the iTHD measurements shown in **Figure 10** are:

- Less than 10 percent with V AC = 230  $V_{rms}$  ( $F_{line}$  = 50 Hz)
- Less than 15 percent with V AC = 120  $V_{rms}$  to 277  $V_{rms}$  ( $F_{line}$  = 60 Hz)

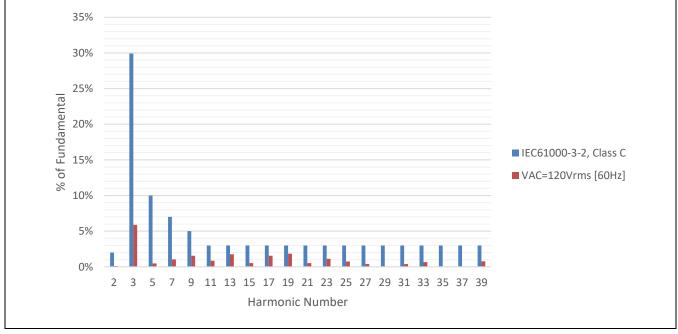


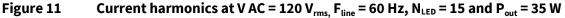




### 5.1.4 Current harmonics

Figure 11 to Figure 13 show the current harmonics measurement compared to the IEC61000-3-2 Class C limit.







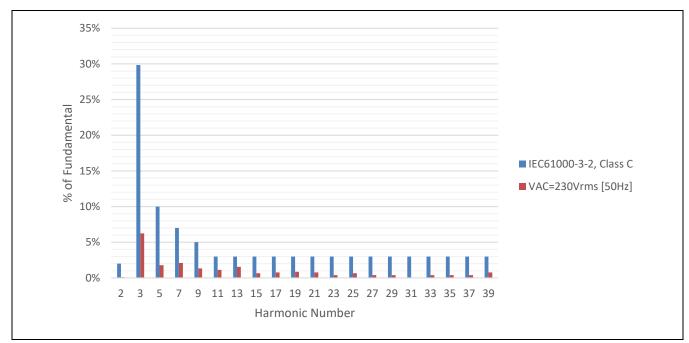


Figure 12 Current harmonics at VAC = 230  $V_{rms}$ ,  $F_{line}$  = 50 Hz,  $N_{LED}$  = 15 and  $P_{out}$  = 35 W

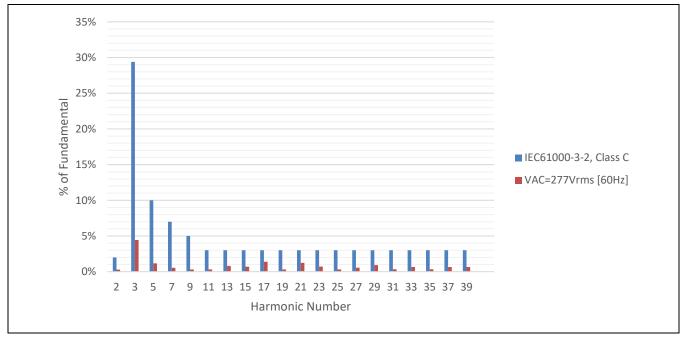


Figure 13 Current harmonics at VAC = 277  $V_{rms}$ ,  $F_{line}$  = 60 Hz,  $N_{LED}$  = 15 and  $P_{out}$  = 35 W

### 5.1.5 Thermal test

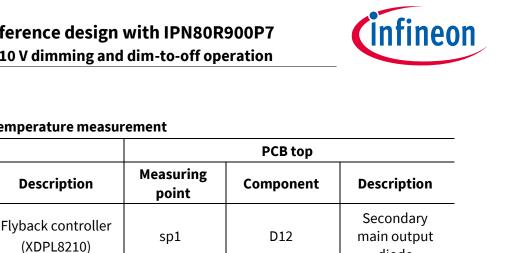
The open-frame thermal test was done on the reference design using an infrared thermography camera (FLIR-T62101) at an ambient temperature of approximately 25°C. The temperature measurements of the following main components (see **Table 3**) were taken after 1 hour running.

Flyback MOSFET

(IPN800R900P7)

CDM10VD V<sub>cc</sub> regulator

depletion MOSFET (BSS169)



Τ1

PCB

sp2

sp3

diode

Flyback

transformer

PCB above Q2

Table 3	Main com	onents fo	r temperat	ture measurer	nent

**PCB** bottom

Component

IC1

Q2

Q3

Measuring

point

sp1

sp2

sp3

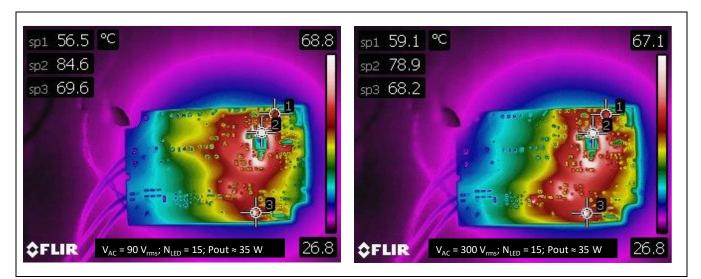


Figure 14 Infrared thermal image result of PCB bottom components

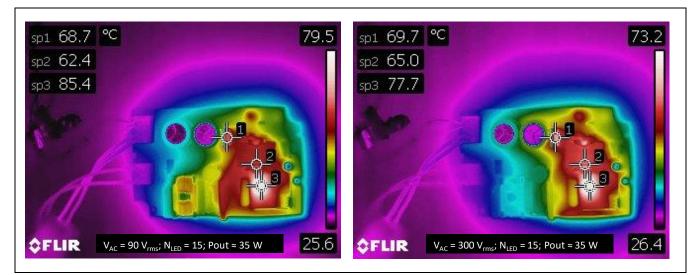


Figure 15 Infrared thermal image result of PCB top components **Engineering Report** 13 of 26



### 5.1.6 Conducted emissions (EN55015B)

The conducted emissions test was performed at full output power, and there is more than a 6 dB margin observed for both live and neutral measurements based on EN55015 standard Class B limits.

The measurement equipment used for this conducted emissions test was Schaffner NNB41 and SMR4503.

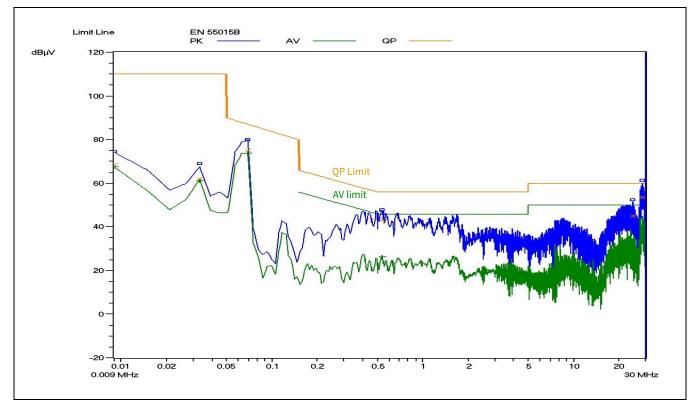
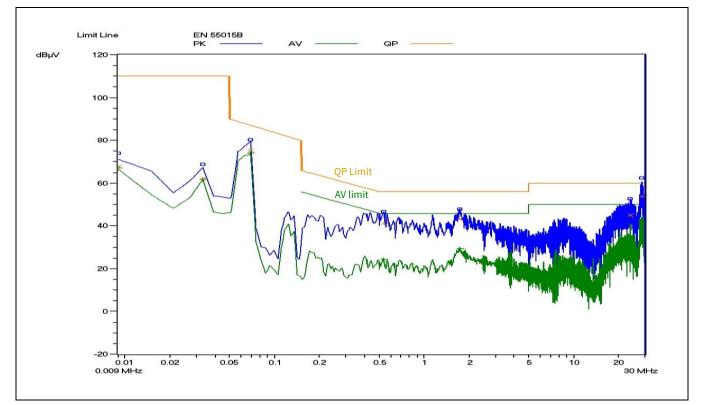


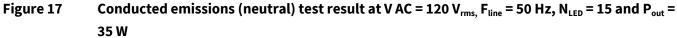
Figure 16 Conducted emissions (live) test result at VAC =  $120 V_{rms}$ ,  $F_{line} = 50 Hz$ ,  $N_{LED} = 15$  and  $P_{out} = 35$ W



## XDPL8210 CDM10VD 35 W reference design with IPN80R900P7 For LED driver with isolated 0 to 10 V dimming and dim-to-off operation

#### Performance





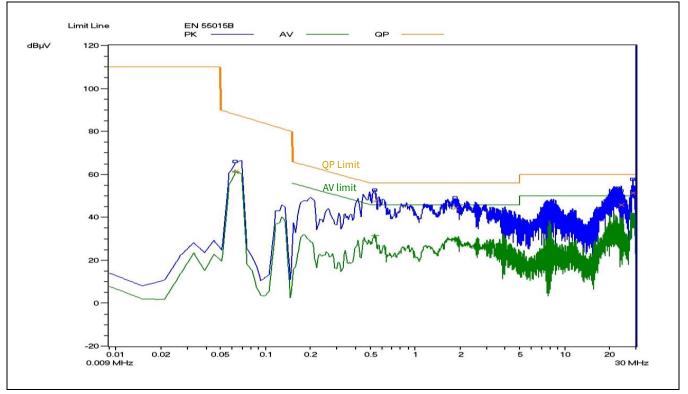
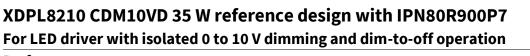


Figure 18 Conducted emissions (live) test result at VAC = 277 V<sub>rms</sub>, F<sub>line</sub> = 50 Hz, N<sub>LED</sub> = 15 and P<sub>out</sub> = 35 W





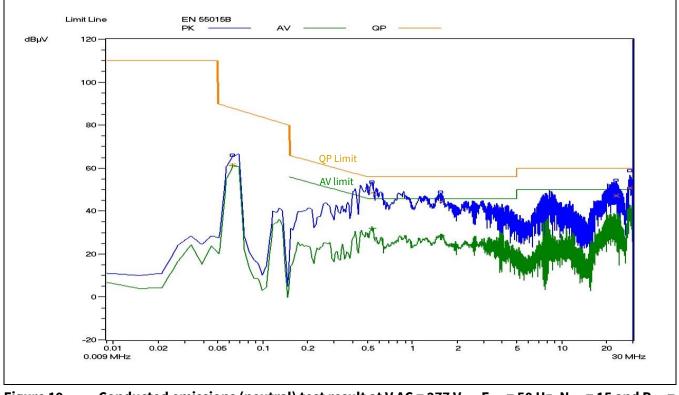


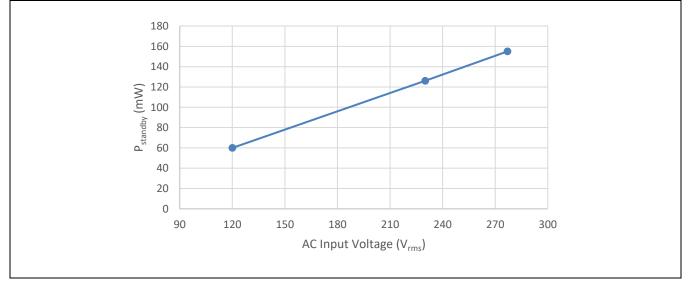
Figure 19 Conducted emissions (neutral) test result at VAC = 277  $V_{rms,} F_{line}$  = 50 Hz,  $N_{LED}$  = 15 and  $P_{out}$  = 35 W

### 5.2 Dimming

The measurement results under dimming condition are presented in this section.

### 5.2.1 Standby power

The standby power under dim-to-off condition ( $V_{DIMMER} = 0 V$ ) is shown in **Figure 20**.







4

6

8

10



Dimmed down, NLED = 14

Dimmed down, NLED = 15

Dimmed down, NLED = 16
 Dimmed down, NLED = 17

Dimmed down, NLED = 18

Dimmed up, NLED = 18

### 5.2.2 LED current dimming curve

0.9

0.8

0.7

0.6

0.5

0.4

0.3

0.2

0.1

0

0.3

0.2

0.1

0 🔶 0

0

2

4

Dimmed off at 1.43 V

LED current (A)

**Figure 21** and **Figure 22** respectively show the LED current dimming curve when the 0 to 10 V dimmer voltage is dimmed down and dimmed up.



2

Dimmed on at 1.53 V

8

10

6

Dimmer voltage (V)



- *Note:* The dimming curve shape is linear by default and is configurable to quadratic (eye-adaptive). The dim-to-off is enabled by default and can be disabled by configuration.
- *Note:* The minimum output current set-point by default is 41.5 mA (5 percent of full output current) and is configurable.

### 5.2.3 **PF and iTHD**

With input voltage V AC = 230  $V_{rms}$ , line frequency  $F_{line}$  = 50 Hz and LED load number  $N_{LED}$  = 14, the PF and iTHD are respectively above 0.9 and below 10 percent over a wide dimming range ( $P_{out}$  = 33 percent to 100 percent), as shown in **Figure 23**.

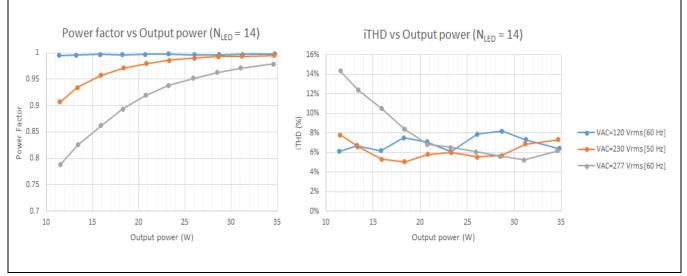


Figure 23 PF and iTHD (dimming condition)

### 5.3 **Protections**

The measurement results under protected condition are presented in this section.

### 5.3.1 Input UVP and maximum power limitation during brown-out

To better protect the primary components e.g. Flyback MOSFET from overheating and magnetics from saturation, XDPL8210 features not only an input UVP (via ZCD and CS pin signal sensing) with configurable threshold for output on/off, but also brown-out maximum power reduction, as shown in **Figure 24**.

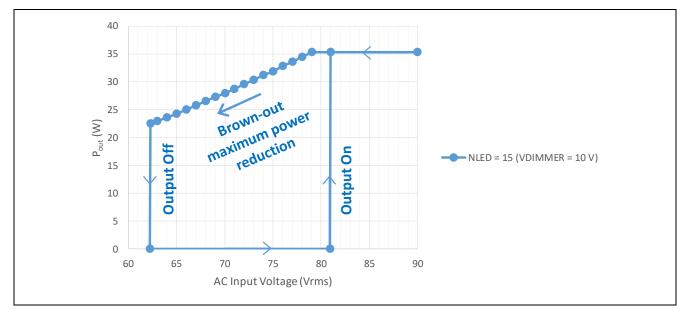


Figure 24 Input UVP and brown-out maximum power reduction

### 5.3.2 Input OVP

Apart from input UVP, XDPL8210 also features input OVP with configurable threshold for output on/off, as shown in **Figure 25**.

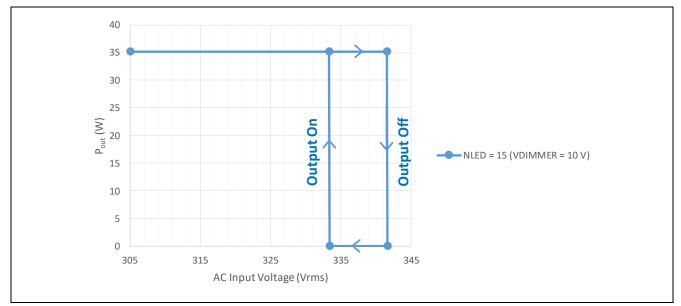


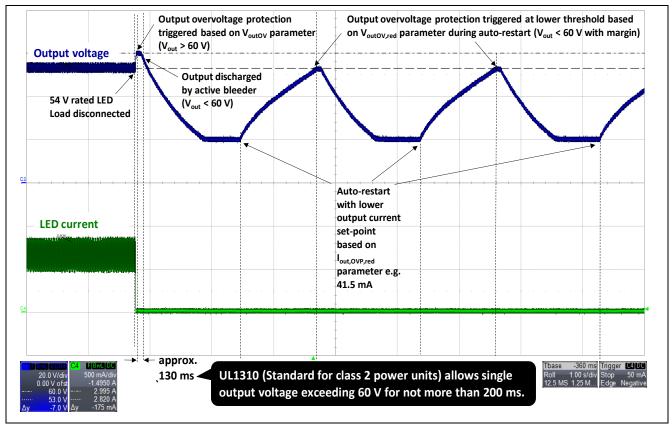
Figure 25 Input UVP and brown-out maximum power reduction

### 5.3.3 Adaptive output OVP

To meet UL1310 (standard for Class 2 power units) for a 54 V rated LED driver with primary-side output current regulation, XDPL8210 features an output OVP with adaptive thresholds (V<sub>outOV</sub> and V<sub>outOV,red</sub>).

Figure 26 shows the captured waveform of the adaptive output OVP triggering after disconnecting the LED load, while **Figure 27** shows the captured waveform of the adaptive output OVP exiting after connecting the LED load.





### Figure 26

Output OVP triggering with adaptive thresholds (V<sub>outov</sub> and V<sub>outov,red</sub>), after disconnecting the LED load

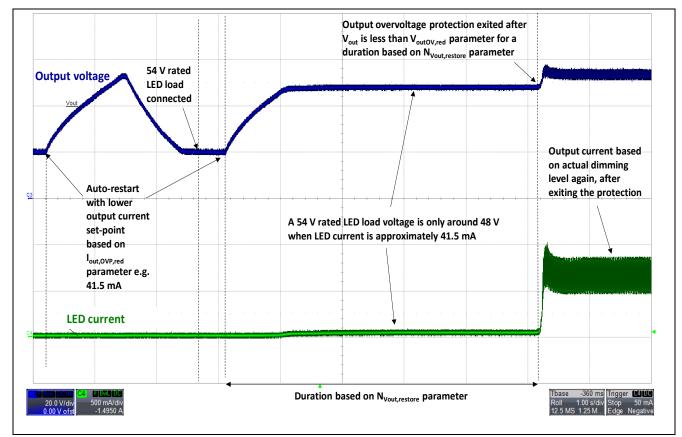


Figure 27 Output OVP exiting after connecting the LED load



### **6 BOM and transformer specifications**

This section provides the BOM and the transformer specifications.

#### Designator Value Part number Manufacturer BR1 Bridge rectifier/4 A/1000 V GBU4M-BP MCC C1, C2 0.1 µF/305 V AC B32922C3104K Epcos C3, C13 SMD size: 1206/1 nF/630 V/COG GRM31B5C2J102JW01L Murata C4, C16, C20, C24 SMD size: 0603/100 nF/50 V/X7R 06035C104K4T4A AVX AVX C5 SMD size: 1206/100 pF/50 V/COG 12065A101K4T2A EEU-FC1H150 E-cap/15 µF/50 V/20 percent C6 Panasonic C7 220 nF/630 V ECW-FA2J224JQ Panasonic C8 E-cap/22 µF/100 V/20 percent UVZ2A220MED1TD Nichicon C9 47 pF/50 V/COG C0603C470J5GAC3112 Kemet C10 SMD size: 1206/6.8 nF/630 V/X7R CGA5H4C0G2J682J115AE TDK Vishav C11 470 p/500 V AC RAD VY1471K31Y5UO6TV0 C12 1500 p/500 V AC RAD Vishay VY1152M41Y5UQ6TV0 C14 MLCC/4.7 µF/100 V/10 percent FG11X7S2A475KRT06 TDK C17 SMD size: 1206/1 µF/100 V/X7R 12061C105K4Z2A AVX C18, C21 E-cap/470 μF/80 V/20 percent ERN1BM471L20OT AiSHi C19 SMD size: 1206/4.7 µF/50 V/X7R CGA5L3X7R1H475K160AE TDK C22 SMD size: 1206/22 nF/50 V/X7R C1206C223K5RACTU KEMET C23 SMD size: 0805/1 nF/50 V/C0G C0805C102J5GAC7210 Kemet SMD size: 0805/100 nF/100 V/X7R C27 C0805C104K1RAC Kemet Standard diode/1 A/1000 V D1 1N4007RLG OnSemi Standard diode/1 A/1000 V D2 1N4007RLG OnSemi D3 ESD diode SOD323 ESD5V0D3-TP MCC Small-signal diode 0.2 A/100 V Diodes D4 BAV19W-7-F D7, D9, D10, D11 Fast diode/0.25 A/250 V BAV103,115 Nexperia D8 Ultra-fast diode/1 A/800 V US1K-13-F Diodes Hyper-fast diode/15 A/300 V D12 VS-15ETH03PBF Vishay Schottky diode/30 V/200 mA/SOD323 NXP D13 PMEG3002EJ F1 Fuse/2 A MCMSF 2A 250 V MultiComp IC1 **Digital Flyback controller** XDPL8210 Infineon IC2 TCLT1103 TCLT1103 Vishay IC3 Dimming interface IC SOT23-6 CDM10VD Infineon J1, J2 20 mm pitch jumper 0.8 mm wire TCW21 250G Pro Power J3, J4, J5 SMD size: 1206/jumper (0 $\Omega$ ) RC1206JR-070RL Yageo/Phycomp Common mode choke 47 mH/0.7 A L1 B82732F2701B001 Epcos L2 Differential choke/470 µH/1.15 A 7447480471 Würth MOV2 Varistor/510 V ERZE08A511 Panasonic NPN/1A/100 V, SOT89 2SC3646T-TD-E OnSemi Q1 Infineon MOSFET/0.9 Ω, 800 V, SOT223 IPN80R900P7 Q2 Q3 BSS169 BSS169 Infineon 2N7002 2N7002 OnSemi 04 Q5 BSS123N BSS123NH6433XTMA1 Infineon

#### Table 4 BOM of main board

### XDPL8210 CDM10VD 35 W reference design with IPN80R900P7 For LED driver with isolated 0 to 10 V dimming and dim-to-off operation BOM and transformer specifications



Designator	Value	Part number	Manufacturer
R3	SMD size: 1206/16 kΩ/1 percent/0.25 W	ERJ-8ENF1602V	Panasonic
R4, R5	SMD size: 1206/18 kΩ/1 percent/0.25 W	ERJ-8ENF1802V	Panasonic
R6	SMD size: 1206/4.7 kΩ/1 percent/0.25 W	CRCW12064K70FKEA	Vishay
R7	SMD size: 1206/20 kΩ/1 percent/0.25 W	WR12X2002FTL	Walsin
R8	SMD size: 1210/1 Ω/1 percent	CRM1206-FX-1R00ELF	Bourns
R9, R10	SMD size: 1210/150 kΩ/1 percent/0.5 W	ERJ14NF1503U	Panasonic
R11	SMD size: 1206/56.2 kΩ/1 percent/0.25 W	CRCW120656K2FKEA	Vishay
R12	SMD size: 0603/ 2.7 kΩ /1 percent	WR06X2701FTL	Walsin
R13	SMD size: 1206/10 Ω/1 percent/0.25 W	RC1206FR-0710RL	Yageo/Phycomp
R14	SMD size: 0603/20 kΩ/1 percent	ERJ-3EKF2002V	Panasonic
R15	SMD size: 1206/300 kΩ/1 percent/0.25 W	WCR1206-300KFI	Welwyn
R16	SMD size: 1210/0.22 Ω/1 percent/1 W	RCWE1210R220FKEA	Vishay
R17	SMD size: 0603/47 kΩ/1 percent	ERJ-3EKF4702V	Panasonic
R18	SMD size: 1206/0 Ω	C1206JR-070RL	Yageo/Phycomp
R20	SMD size: 0603/39 kΩ/1 percent	ERJ-3EKF3902V	Panasonic
R21	SMD size: 3216/200 kΩ/1 percent/0.25 W	MCWR12X2003FTL	MultiComp
R22	SMD size: 0805/330 kΩ/1 percent	MCWF08P3303FTL	MultiComp
R23	SMD size: 0805/200 kΩ/1 percent	CRCW0805200KFKEAC	Vishay
R24, R25,			
R26	SMD size: 3225/3.0 kΩ/0.5 W	CRCW12103K00FKEA	Vishay
R27	SMD size: 1206/0 Ω	RC1206JR-070RL	Yageo/Phycomp
R28	SMD size: 0603/1 MΩ/1 percent/0.1 W	CRCW06031M00FKEAC	Vishay
R29	SMD size: 0805/0 Ω	RC0805JR-070RL	Yageo/Phycomp
R30	SMD size: 0603/0 Ω	RC0603FR-070RL	Yageo/Phycomp
R32, R33	SMD size: 1206/10 MΩ/1 percent/0.25 W	RCV120610M0FKEA	Vishay
	PQ2020; Lp = 566 μH; Np = 58; Ns = 17; Na = 15;		
T1	Nsec_aux = 15	750343465 Rev00	Würth
X1	250 to 203	250-203	WAGO
	Post header, 2.54 mm pitch, 3-pin, vertical,		
<b>K</b> 2	single row	MC34631	MultiComp
(3	250 to 204	250-204	WAGO
ZD1	Zener, 16 V, 5 percent	BZX384-C16	NXP
ZD2, ZD3,			
ZD5	Zener, 12 V, 5 percent	BZX384C12-E3-08	Vishay
ZD4	Zener, 18 V, 2 percent	BZX384B18-E3-08	Vishay



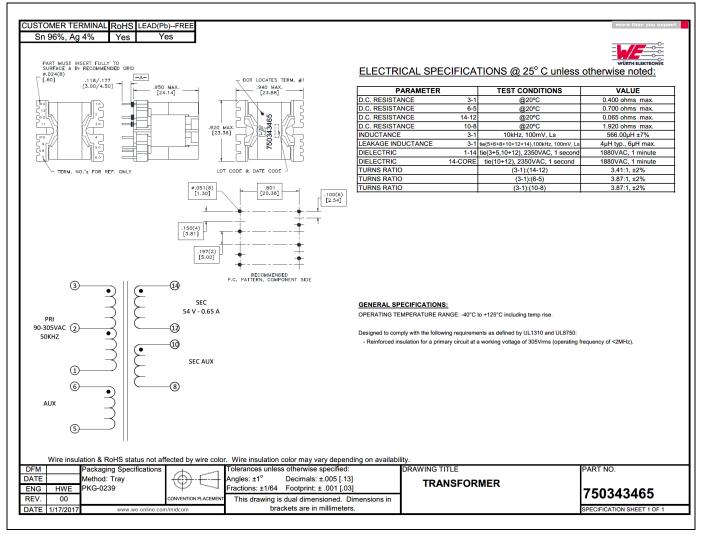


Figure 28 Flyback transformer (T1) specifications



7 References

[1] XDPL8210 datasheet



### **Revision history**

Document version	Date of release	Description of changes
V 1.1	2021-07-01	Change C22 value from 220 nF to 22 nF in schematic and BOM Remove "and DC input with 127 V to 432 V" text from Section 2
V 1.0	2019-02-14	Initial version

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